# NSN 5962-01-361-6509

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## Maximum Power Dissipation Rating:

960.0 milliwatts

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## Features Provided:

Burn in and electrostatic sensitive and programmed

#### **Inclosure Material:**

Ceramic

## Inclosure Configuration:

Dual-in-line

#### Input Circuit Pattern:

12 input

#### Case Outline Source And Designator:

D-6 mil-m-38510

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

## Memory Device Type:

Prom

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

18 printed circuit

## Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

## Fiig:

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